

# PSMN1R4-100CSE

N-channel, 100 V, 1.42 mOhm, MOSFET with enhanced SOA in CCPAK1212i package

6 December 2024

Product data sheet

# 1. General description

N-channel enhancement mode MOSFET in a CCPAK1212i package qualified to 175 °C. Part of Nexperia's Application Specific MOSFETs (ASFETs) for Hotswap and Soft Start. The PSMN1R4-100CSE delivers very low R<sub>DSon</sub> and enhanced safe operating area performance in a high-reliability copper-clip package (CCPAK1212).

PSMN1R4-100CSE complements the latest "hot-swap" controllers - robust enough to withstand substantial inrush currents during turn-on, low  $R_{DSon}$  to minimize I²R losses and deliver optimum efficiency when turned fully ON.

### 2. Features and benefits

- · Fully optimized Safe Opertating Area (SOA) for superior linear mode operation
- Low R<sub>DSon</sub> for low I<sup>2</sup>R conduction losses
- · CCPAK1212i package for applications that demand the highest performance and reliability
- Inverted package, suitable for top-side cooling

# 3. Applications

- Hot swap
- · Load switch
- Soft start
- E-fuse
- Telecommunication systems based on a 48 V backplane/supply rail

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	100	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>		-	-	340	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	-	935	W
Tj	junction temperature			-55	-	175	°C
Static characte	Static characteristics						
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 10 V; $I_{D}$ = 25 A; $T_{j}$ = 25 °C; Fig. 11		-	1.12	1.42	mΩ
Dynamic chara	Dynamic characteristics						
$Q_{GD}$	gate-drain charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 10 V;		11	36.5	84	nC
Q <sub>G(tot)</sub>	total gate charge	T <sub>j</sub> = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>		122	244	366	nC



# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		
2	S	source		
3	S	source	12 11 10 9 8 7	
4	S	source		
5	S	source		
6	G	gate		D
7	D	drain		
8	D	drain		G T T
9	D	drain		mbb076 S
10	D	drain	1 2 3 4 5 6	
11	D	drain	sot8005a_sv	
12	D	drain	CCPAK1212i (SOT8005A)	
mb	D	mounting base; connected to drain		

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package		
	Name	Description	Version
PSMN1R4-100CSE		Plastic, surface mounted copper clip package (CCPAK1212i); 12 terminals; 2.0 mm pitch, 12 mm × 12 mm × 2.5 mm body	SOT8005A

# 7. Marking

## Table 4. Marking codes

Type number	Marking code
PSMN1R4-100CSE	XP1E4S10C

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).  $T_i$  = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	100	V
$V_{DGR}$	drain-gate voltage	25 °C ≤ $T_j$ ≤ 175 °C; $R_{GS}$ = 20 kΩ		-	100	V
$V_{GS}$	gate-source voltage			-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	935	W
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>		-	340	Α
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>		-	340	Α
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 °C$ ; Fig. 3		-	2140	Α
T <sub>stg</sub>	storage temperature			-55	175	°C
Тј	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
Source-drain o	diode		'	'	'	
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C		-	340	Α
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 \degree C$		-	2140	Α
Avalanche rug	gedness				•	
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$I_D$ = 98.95 A; $V_{sup} \le 100$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; unclamped; $t_p$ = 175 μs; Fig. 4	[1]	-	1130	mJ
I <sub>AS</sub>	non-repetitive avalanche current	$V_{sup} = 100 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $R_{GS} = 50 \Omega; Fig. 4$	[1]	-	98.95	A

#### [1] Protected by 100% test

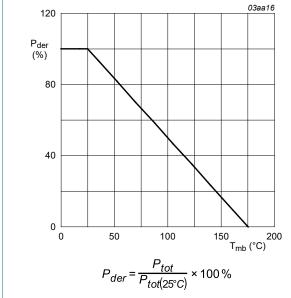
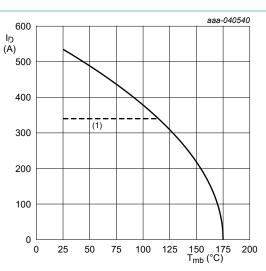
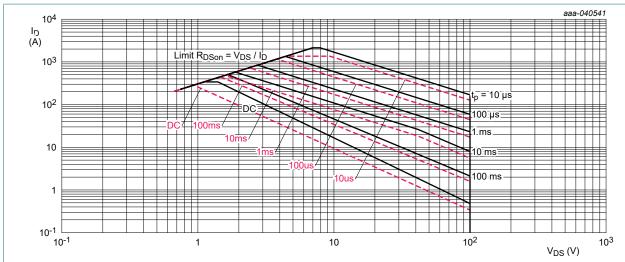


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



 $V_{GS} \ge 10 \text{ V}$  (1) 340 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature



 $T_{mb}$  = 25 °C (solid black line);  $T_{mb}$  = 125 °C (red dashed line);  $I_{DM}$  is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

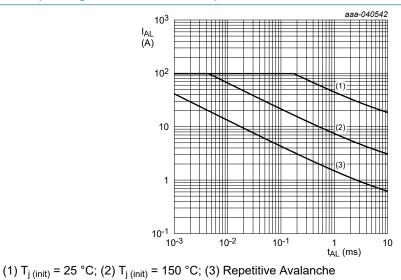


Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

### 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	0.123	0.16	K/W
R <sub>th(j-a)</sub>	thermal resistance from	Fig. 6	-	58	-	K/W
	junction to ambient	Fig. 7	-	29	-	K/W

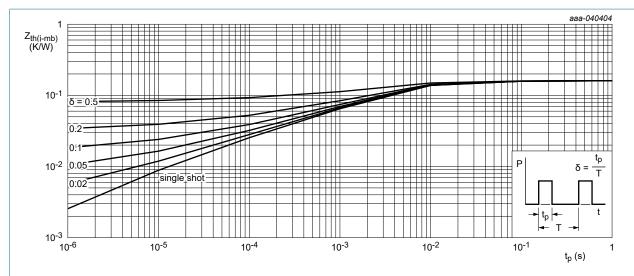


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

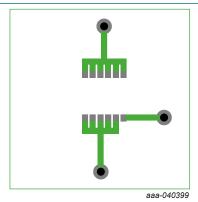
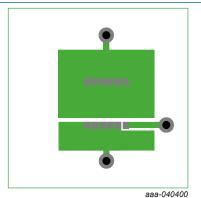


Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

70 µm thick copper on FR4 board



Copper area 25.4mm square; 70  $\mu$ m thick on FR4 board

Fig. 7. PCB layout for thermal resistance from junction to ambient

# 10. Characteristics

Table 7. Chara Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		Conditions	IVIIII	тур	IVIAX	Offic
Static charac		050 4 1/ 01/ 7 05/00	400			1.7
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	100	-	-	V
	-	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$	90	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	2	2.8	3.6	V
	voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C}$	-	1.76	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$	-	3.3	-	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T <sub>j</sub> ≤ 150 °C	-	-6.93	-	mV/K
$I_{\rm DSS}$	drain leakage current	V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.12	1.6	μΑ
		V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C	-	39	160	μΑ
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 11	-	1.12	1.42	mΩ
		$V_{GS}$ = 10 V; $I_D$ = 25 A; $T_j$ = 100 °C; Fig. 12	-	1.9	2.3	mΩ
		$V_{GS}$ = 10 V; $I_D$ = 25 A; $T_j$ = 175 °C; Fig. 12	-	2.6	3.3	mΩ
$R_G$	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	0.51	1.03	2.05	Ω
Dynamic cha	racteristics					
Q <sub>G(tot)</sub>	total gate charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>	122	244	366	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}$	-	218	-	nC
Q <sub>GS</sub>	gate-source charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 10 V;	49	81.5	114	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge	T <sub>j</sub> = 25 °C; <u>Fig. 13; Fig. 14</u>	-	53	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	29	-	nC
$Q_{GD}$	gate-drain charge		11	36.5	84	nC
V <sub>GS(pl)</sub>	gate-source plateau voltage	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 50 V; T <sub>j</sub> = 25 °C; Fig. 13; Fig. 14	-	4.5	-	V
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 0 V; f = 0.5 MHz;	11153	18588	26023	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 15</u>	2453	4089	6542	pF
C <sub>rss</sub>	reverse transfer capacitance		11	115	299	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = 50 \text{ V}; R_L = 2 \Omega; V_{GS} = 10 \text{ V};$	-	65	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	66	-	ns
$t_{d(off)}$	turn-off delay time		-	142	-	ns
t <sub>f</sub>	fall time	-	-	86	-	ns
Source-drain						
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 25 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C; <u>Fig. 16</u>	_	0.77	1	V
טט		0 - / 00, -j				

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>rr</sub>	_	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	62	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = 50 V; T <sub>j</sub> = 25 °C; <u>Fig. 17</u>	-	84	-	nC

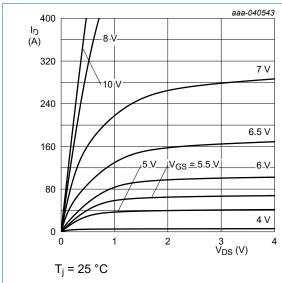


Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

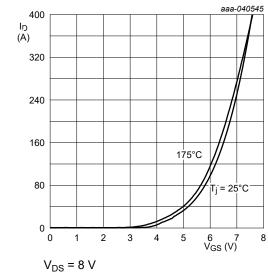


Fig. 10. Transfer characteristics; drain current as a function of gate-source voltage; typical values

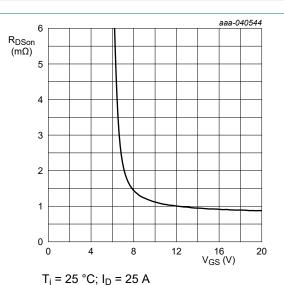


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

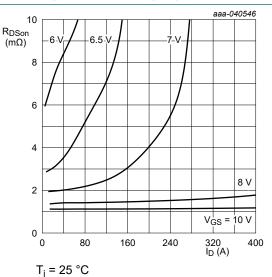


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

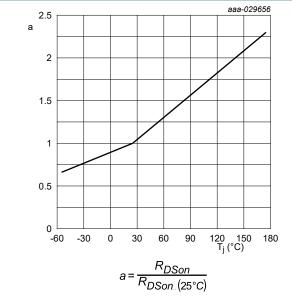


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

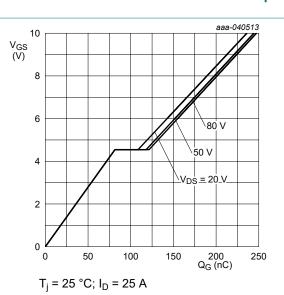


Fig. 13. Gate-source voltage as a function of gate charge; typical values

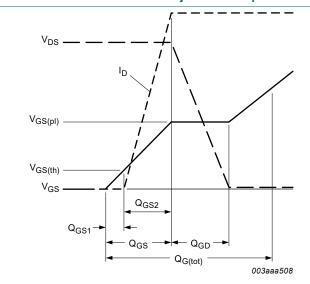


Fig. 14. Gate charge waveform definitions

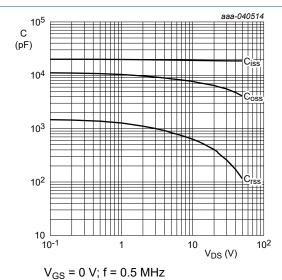


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

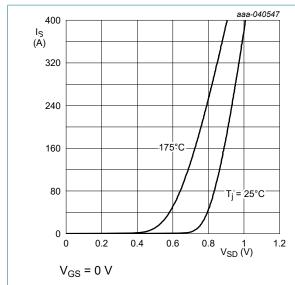


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

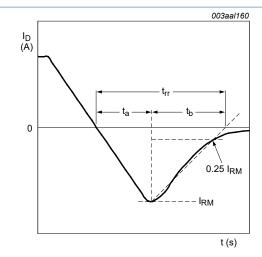


Fig. 17. Reverse recovery timing definition

# 11. Package outline

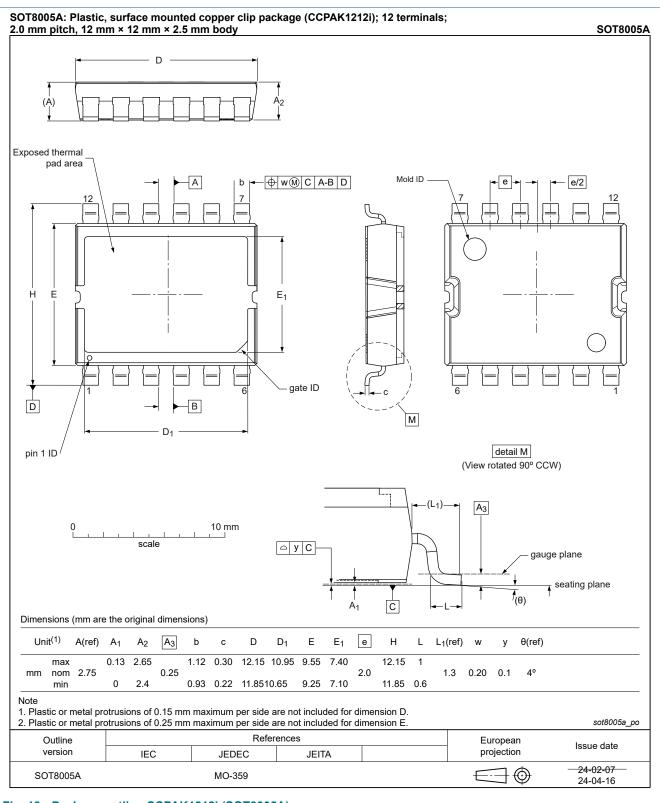
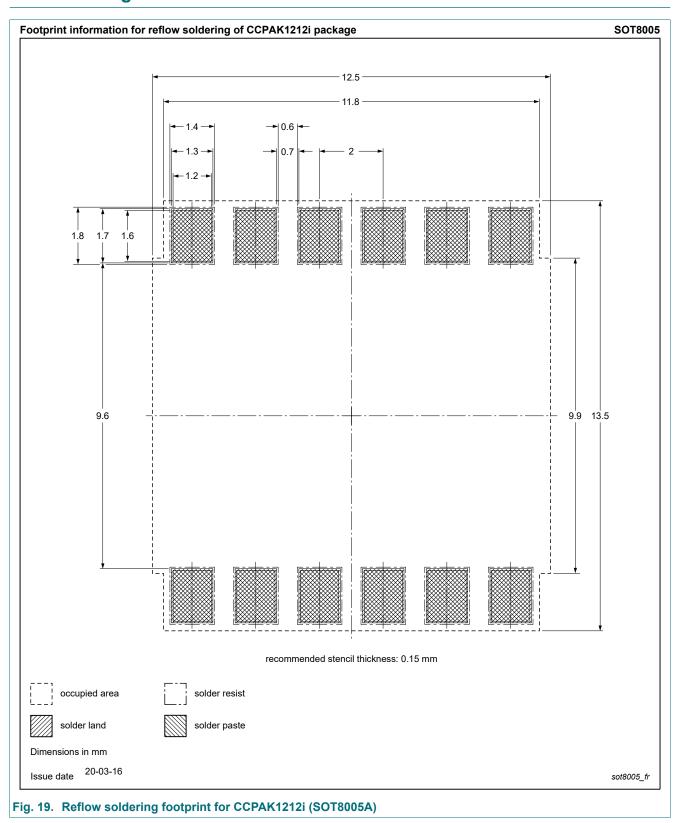


Fig. 18. Package outline CCPAK1212i (SOT8005A)

# 12. Soldering



# 13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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